L Number	Hits	Search Text	DB	l mima at a
1	15	349/\$.ccls. and "indium tin oxide" with	USPAT;	Time stamp
1	ľ	doped with antimonv	US-PGPUB	2004/01/24 14:43
2	60	349/\$.ccls. and "indium tin oxide" with	USPAT;	2004/01/01
İ		doped	-	2004/01/24 14:43
3	45	(349/\$.ccls. and "indium tin oxide" with	US-PGPUB	1
ļ		doped) not (349/\$.ccls. and "indium tin	USPAT;	2004/01/24 14:46
	i	oxide" with doped with antimony)	US-PGPUB	
4	26	349/\$.ccls. and (antimony near2 (indium or		
	ļ	ito))	1	2004/01/24 14:48
5	257		US-PGPUB	
		districts: and nesa	USPAT;	2004/01/24 14:49
6	8	349/\$.ccls. and nesa with antimony	US-PGPUB	
	•	oistviceis. and nesa with antimony	USPAT;	2004/01/24 14:53
7	1	349/\$.ccls. and ((ito or "indium tin	US-PGPUB	
	-	oxide") with additional\$ with dop\$)	USPAT;	2004/01/24 14:54
8	165	349/\$.ccls. and dop\$ with ito	US-PGPUB	
	100	343/3.ccis. and dops with ito	USPAT;	2004/01/24 14:54
10	39	"donad itall	US-PGPUB	
- "	33	"doped ito"	USPAT;	2004/01/24 14:55
_	250	240/0 1	US-PGPUB	
	250	349/\$.ccls. and sensor and ito and silicon	USPAT;	2004/01/24 14:41
_	100	240/0	US-PGPUB	
_	109	349/\$.ccls. and sensor and ito and silicon	USPAT;	2004/01/23 18:18
_	00	and oxide and nitride	US-PGPUB	1 2 3 7 2 3 10:10
_	92	photosensitive and sensor	USPAT;	2004/01/23 18:18
		and ito	US-PGPUB	2001/01/25 10:18
_	25	349/\$.ccls. and "photosensitive element"	USPAT;	2004/01/23 18:19
	i.		US-PGPUB	2004/01/25 10.19
-	22	349/\$.ccls. and "photosensitive element"	USPAT	2004/01/23 18:33
-	1	5619033.pn.	USPAT	2004/01/23 18:23
-	285	349/\$.ccls. and photodiode	USPAT	2004/01/23 18:36
_	27	349/\$.ccls. and photodiode and ito and	USPAT	2004/01/23 18:34
		"silicon oxide" and "silicon nitride"		2004/01/23 18:34
-	10	"5619033"	USPAT	2004/01/23 18:50
-	2	349/\$.ccls. and "doped ito"	USPAT	2004/01/23 19:30
-	300	257/\$.ccls. and "photosensitive element"	USPAT	2004/01/23 19:30
-	55	25//\$.ccls. and "photosensitive element"	USPAT	2004/01/23 19:31
ľ		and ito		2004/01/23 19:31
-	30	257/\$.ccls. and "photosensitive element"	USPAT	2004/01/23 19:43
]	İ	and ito and nitride and oxide and silicon		2004/01/23 19:43
- [2	25//\$.ccls. and "photosensitive element"	USPAT	2004/01/23 19:34
1		and (ito with doped) and nitride and oxide	ODIAL	2004/01/23 19:34
		and silicon]
-	1	"photosensitive element" and (dop\$ near3	USPAT	2004/01/02 15 5=
		ito)	OSEMI	2004/01/23 19:35
-	7	257/\$.ccls. and "photosensitive element"	tic Dam	000440445
ļ	1	and ito and sinx and siox	USPAT	2004/01/23 19:45
-	2	438/\$.ccls. and "photosensitive element"	II C D A M	000440445
		and ito and sinx and siox	USPAT	2004/01/23 19:45
-	57	349/\$.ccls. and (dop\$ near3 ito)	Hanne	
-		349/\$.ccls. and ato	USPAT	2004/01/23 22:39
- !	34	257/\$.ccls. and ato	USPAT	2004/01/23 22:42
- 1	57	tanaka.in. and sakae.in.	USPAT	2004/01/23 22:44
	<u>_</u> 1	and Sakae.In.	USPAT	2004/01/23 22:51